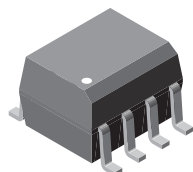
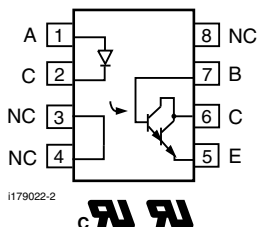




Optocoupler, Photodarlington Output, Low Input Current, High Gain, with Base Connection



I179074



I179022-2



FEATURES

- Isolation test voltage, 4000 V_{RMS}
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



RoHS
COMPLIANT

AGENCY APPROVALS

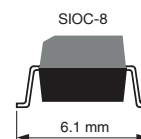
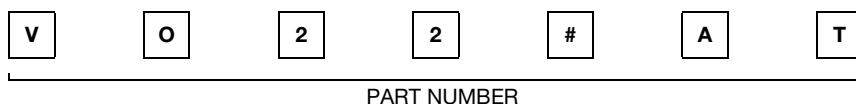
- UL1577, file no. E52744 system code Y
- cUL - file no. E52744, equivalent to CSA bulletin 5A

DESCRIPTION

The VO221AT, VO222AT, VO223AT are high current transfer ratio (CTR) optocouplers with a gallium arsenide infrared LED emitter and a silicon NPN photodarlington transistor detector.

The device has a CTR tested at 1 mA LED current. This low drive current permits easy interfacing from CMOS to LSTTL or TTL.

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)		
UL, cUL	> 100	> 200	> 500
SOIC-8	VO221AT	VO222AT	VO223AT

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Peak reverse voltage		V _R	6	V
Peak forward current	1 μs, 300 pps	I _{FM}	1	A
Forward continuous current		I _F	60	mA
Power dissipation		P _{diss}	90	mW
Derate linearly from 25 °C			1.2	mW/°C
OUTPUT				
Collector emitter breakdown voltage		BV _{CEO}	30	V
Emitter collector breakdown voltage		BV _{ECO}	5	V
Collector base breakdown voltage		BV _{CBO}	70	V
I _{Cmax} , DC		I _{Cmax} , DC	50	mA
I _{Cmax} , AC	t < 1 ms	I _{Cmax} , AC	100	mA
Power dissipation		P _{diss}	150	mW

VO221AT, VO222AT, VO223AT



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ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
COUPLER				
Derate linearly from $25\text{ }^{\circ}\text{C}$			2	mW/ $^{\circ}\text{C}$
Isolation test voltage	$t = 1\text{ s}$	V_{ISO}	4000	V_{RMS}
Total package dissipation (at $25\text{ }^{\circ}\text{C}$ ambient) (LED and detector)		P_{tot}	240	mW
Derate linearly from $25\text{ }^{\circ}\text{C}$			3.2	mW/ $^{\circ}\text{C}$
Storage temperature		T_{stg}	- 40 to + 150	$^{\circ}\text{C}$
Operating temperature		T_{amb}	- 40 to + 100	$^{\circ}\text{C}$
Soldering time at $260\text{ }^{\circ}\text{C}$		T_{sld}	10	s

Note

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = 1\text{ mA}$	V_F		1	1.5	V
Reverse current	$V_R = 6\text{ V}$	I_R		0.1	100	μA
Capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$	C_O		25		pF
OUTPUT						
Collector emitter breakdown voltage	$I_C = 100\text{ }\mu\text{A}$	BV_{CEO}	30			V
Emitter collector breakdown voltage	$I_C = 10\text{ }\mu\text{A}$	BV_{ECO}	5			V
Collector base breakdown voltage	$I_C = 10\text{ }\mu\text{A}$	BV_{CBO}	70			V
Collector emitter leakage current	$V_{CE} = 20\text{ V}$	I_{CEO}			40	nA
Collector base current		I_{CBO}			1	nA
Emitter base current		I_{EBO}			1	nA
Collector emitter capacitance	$V_{CE} = 10\text{ V}$	C_{CE}		3.4		pF
Saturation voltage, collector emitter	$I_{CE} = 0.5\text{ mA}$	V_{CEsat}			1	V
COUPLER						
Capacitance (input to output)		C_{IO}		0.5		pF

Note

- Minimum and maximum values are tested requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	$I_F = 1\text{ mA}$, $V_{CE} = 5\text{ V}$	VO221AT	CTR_{DC}	100			%
		VO222AT	CTR_{DC}	200			%
		VO223AT	CTR_{DC}	500			%

SWITCHING CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time	$V_{CC} = 10\text{ V}$, $R_L = 100\ \Omega$, $I_F = 5\text{ mA}$	t_{on}		3		μs
Turn-off time	$V_{CC} = 10\text{ V}$, $R_L = 100\ \Omega$, $I_F = 5\text{ mA}$	t_{off}		3		μs

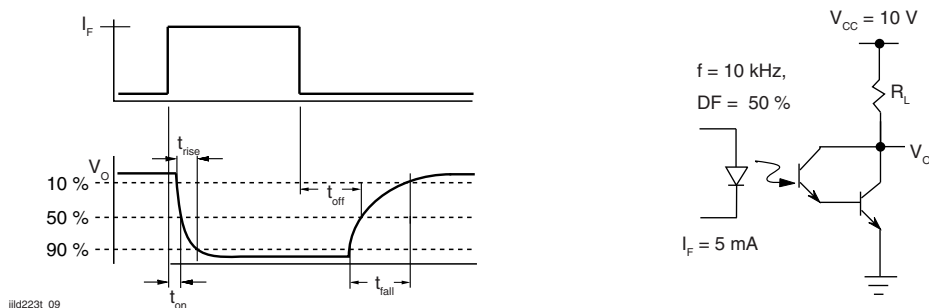


Fig. 1 - Switching Test Circuit

SAFETY AND INSULATION RATINGS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC 68 part 1)				40/100/21		
Polution degree				2		
Comparative tracking index		CTI	175		399	
Isolation test voltage	1 s	V_{ISO}	4000			V_{RMS}
Peak transient overvoltage		V_{IOTM}	6000			V
Peak insulation voltage		V_{IORM}	560			V
Resistance (input to output)		R_{IO}		100		GW
Safety rating - power output		P_{SO}			350	mW
Safety rating - input current		I_{SI}			150	mA
Safety rating - temperature		T_{SI}			165	$^{\circ}\text{C}$
External creepage distance			4			mm
External clearance distance			4			mm
Internal creepage distance			3.3			mm
Insulation thickness			0.2			mm

Note

- As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

Vishay Semiconductors Optocoupler, Photodarlington
Output, Low Input Current, High
Gain, with Base Connection

TYPICAL CHARACTERISTICS ($T_{amb} = 25^\circ\text{C}$, unless otherwise specified)

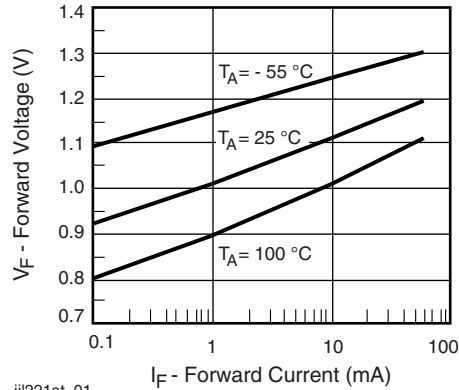


Fig. 1 - Forward Voltage vs. Forward Current

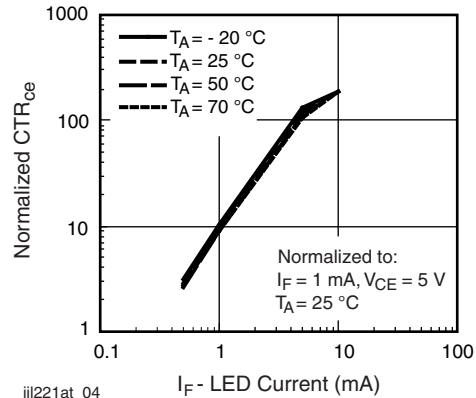


Fig. 4 - Normalized CTR_{CE} vs. LED Current

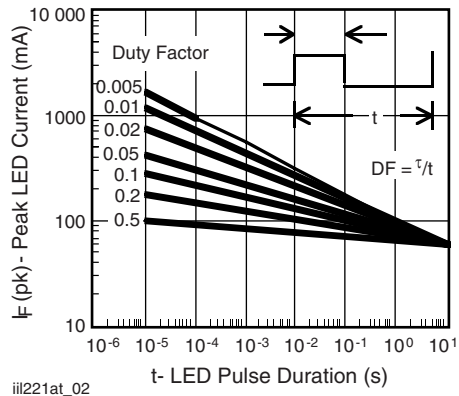


Fig. 2 - Peak LED Current vs. Duty Factor, τ

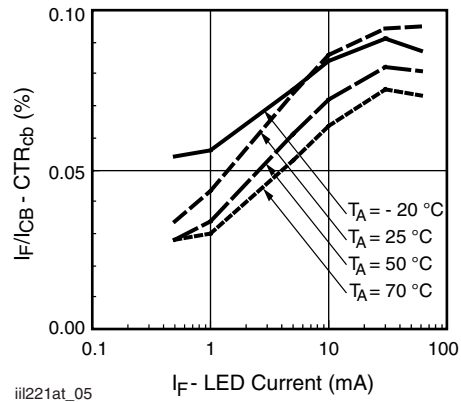


Fig. 5 - CTR_{CB} vs. LED Current

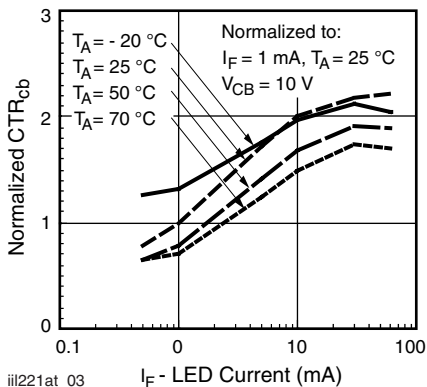


Fig. 3 - Normalized CTR_{CB} vs. I_F

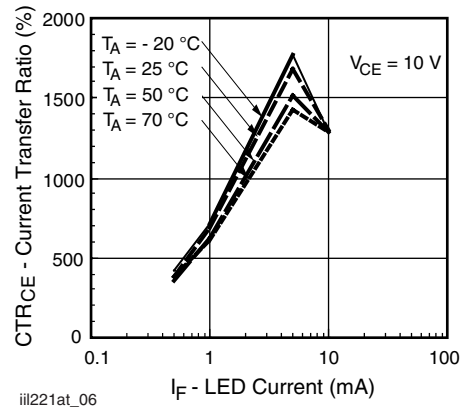
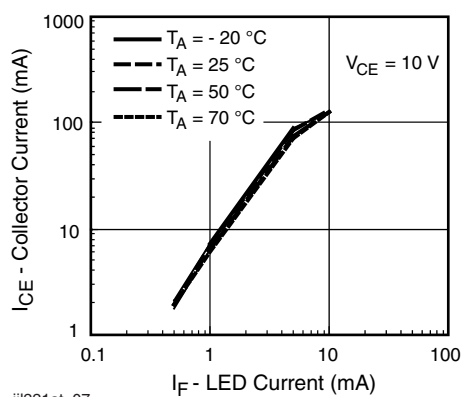
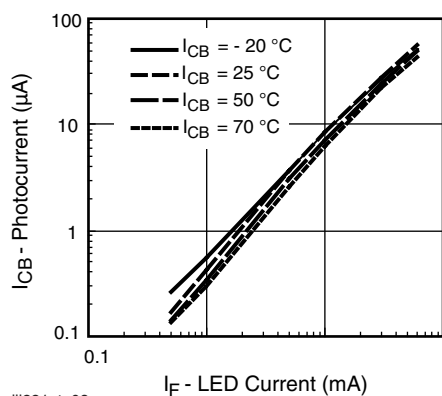


Fig. 6 - CTR vs. LED Current



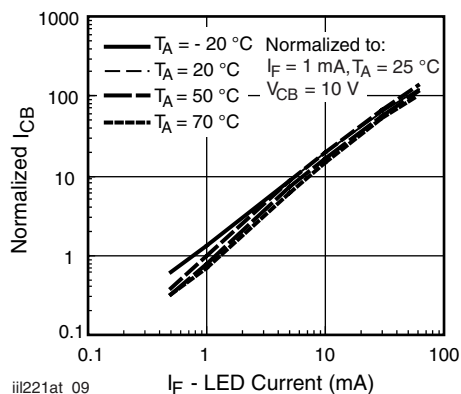
iii221at_07

Fig. 7 - Collector Current vs. LED Current



iii221at_08

Fig. 8 - Photocurrent vs. LED Current



iii221at_09

Fig. 9 - Normalized I_{CB} vs. I_F

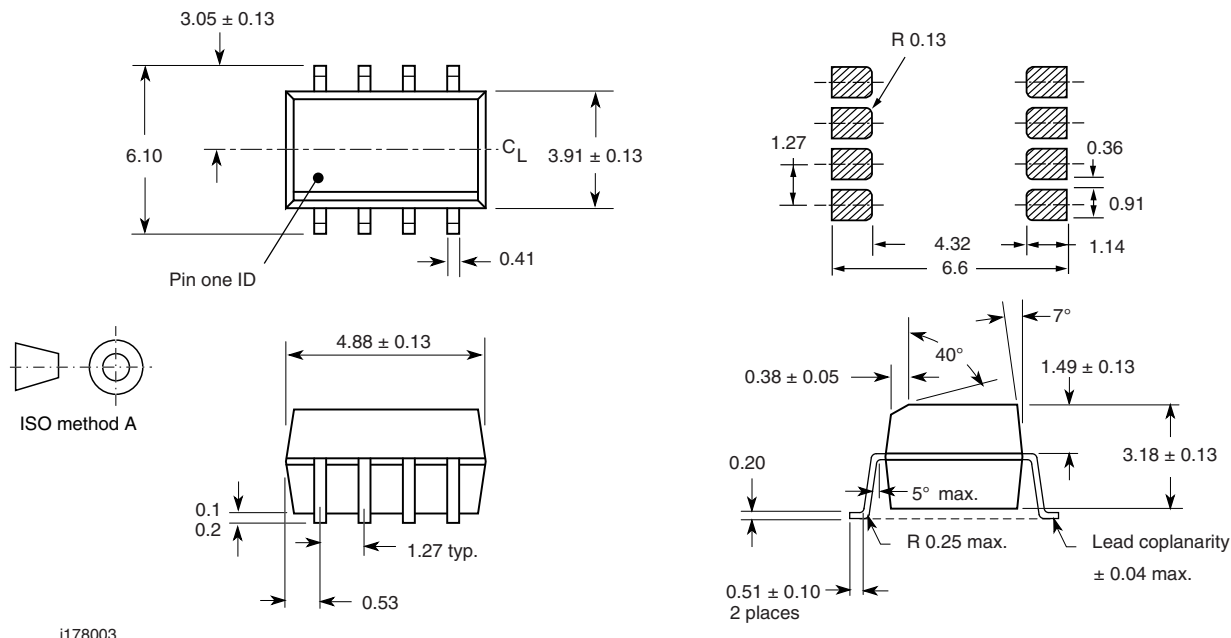
VO221AT, VO222AT, VO223AT



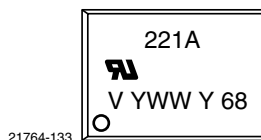
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PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (example)



Note

- Tape and reel suffix (T) is not part of the package marking.



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